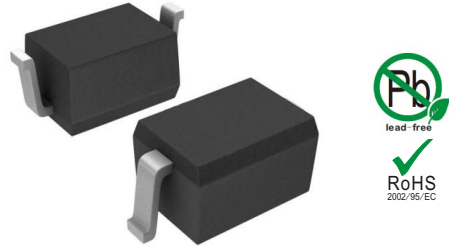


Features

- 350W peak pulse power (8/20us)
- Protects one data or power line
- Low leakage: nA level
- Stand-off Voltage: 3.3 V ~ 36 V
- Low clamping voltage
- RoHS Compliant



IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 $\pm 30\text{kV}$ (contact) $\pm 30\text{kV}$ (air)
- IEC61000-4-4 (EFT) 40A (5/50ns)

SOD-323

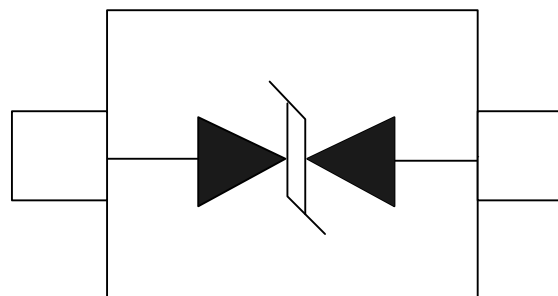
Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation
- Networking and Telecom
- Serial and Parallel Ports.
- Peripherals

Mechanical Data

- Package: SOD-323
- Case Material: "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below

Schematic & PIN Configuration



SOD-323

Absolute Maximum Rating

PTD322H450S3B35			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μ s)	Ppk	350	W
Peak Pulse Current (8/20 μ s)	Ipp	20	A
ESD per IEC 61000-4-2 (Air)	VESD	\pm 30	kV
ESD per IEC 61000-4-2 (Contact)		\pm 30	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$ C
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}$ C
PTD322H200S5B35			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μ s)	Ppk	350	W
Peak Pulse Current (8/20 μ s)	Ipp	17	A
ESD per IEC 61000-4-2 (Air)	VESD	\pm 30	kV
ESD per IEC 61000-4-2 (Contact)		\pm 30	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$ C
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}$ C
PTD322H75S12B35			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μ s)	Ppk	350	W
Peak Pulse Current (8/20 μ s)	Ipp	11	A
ESD per IEC 61000-4-2 (Air)	VESD	\pm 30	kV
ESD per IEC 61000-4-2 (Contact)		\pm 30	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$ C
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}$ C

Absolute Maximum Rating

PTD322H68S15B35			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μ s)	Ppk	350	W
Peak Pulse Current (8/20 μ s)	Ipp	10	A
ESD per IEC 61000-4-2 (Air)	VESD	\pm 30	kV
ESD per IEC 61000-4-2 (Contact)		\pm 30	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$ C
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}$ C
PTD322H57S24B35			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μ s)	Ppk	350	W
Peak Pulse Current (8/20 μ s)	Ipp	7	A
ESD per IEC 61000-4-2 (Air)	VESD	\pm 30	kV
ESD per IEC 61000-4-2 (Contact)		\pm 30	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$ C
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}$ C
PTD322H35S36B35			
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μ s)	Ppk	350	W
Peak Pulse Current (8/20 μ s)	Ipp	5	A
ESD per IEC 61000-4-2 (Air)	VESD	\pm 30	kV
ESD per IEC 61000-4-2 (Contact)		\pm 30	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}$ C
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}$ C

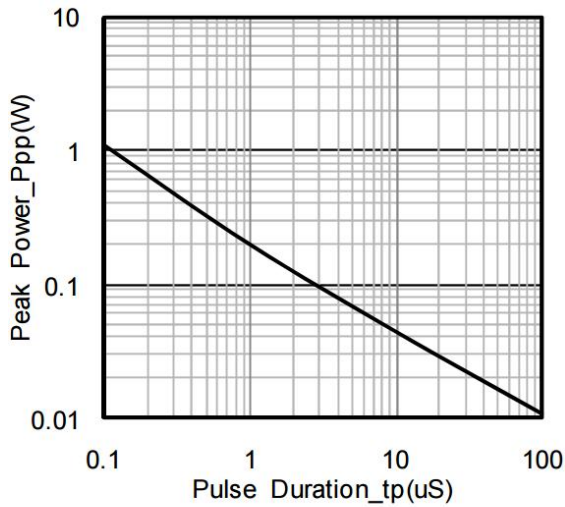
Absolute Maximum Rating

PTD322H450S3B35						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			3.3	V	
Breakdown Voltage	V_{BR}	4.0			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			40	μA	$V_{RWM} = 3.3\text{V}$
Clamping Voltage	V_C		7		V	$I_{PP} = 1\text{A}$ (8 x 20 μs pulse)
Clamping Voltage	V_C			19	V	$I_{PP} = 20\text{A}$ (8 x 20 μs pulse)
Junction Capacitance	C_J		450		pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$
PTD322H200S5B35						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			5	V	
Breakdown Voltage	V_{BR}	6.2			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			10	μA	$V_{RWM} = 5\text{V}$
Clamping Voltage	V_C		9.8		V	$I_{PP} = 1\text{A}$ (8 x 20 μs pulse)
Clamping Voltage	V_C			21	V	$I_{PP} = 17\text{A}$ (8 x 20 μs pulse)
Junction Capacitance	C_J		200		pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$
PTD322H75S12B35						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			12	V	
Breakdown Voltage	V_{BR}	13.3			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			1	μA	$V_{RWM} = 12\text{V}$
Clamping Voltage	V_C		19		V	$I_{PP} = 1\text{A}$ (8 x 20 μs pulse)
Clamping Voltage	V_C			32	V	$I_{PP} = 11\text{A}$ (8 x 20 μs pulse)
Junction Capacitance	C_J		75		pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

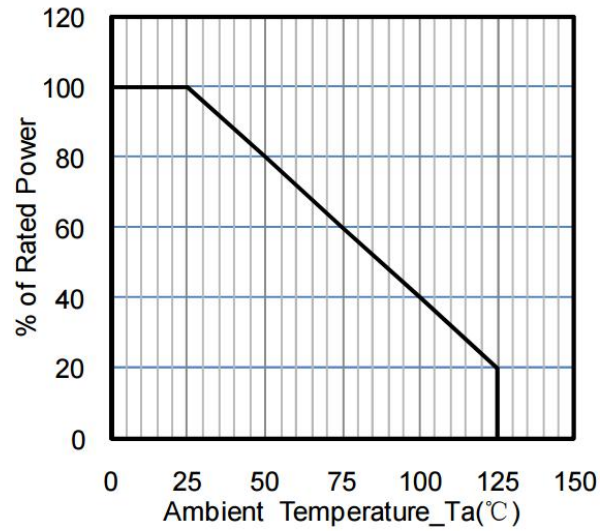
Absolute Maximum Rating

PTD322H68S15B35						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			15	V	
Breakdown Voltage	V_{BR}	16.7			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			1	μA	$V_{RWM} = 15\text{V}$
Clamping Voltage	V_C		24		V	$I_{PP} = 1\text{A}$ (8 x 20 μs pulse)
Clamping Voltage	V_C			38	V	$I_{PP} = 10\text{A}$ (8 x 20 μs pulse)
Junction Capacitance	C_J		68		pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$
PTD322H57S24B35						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			24	V	
Breakdown Voltage	V_{BR}	26.7			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			1	μA	$V_{RWM} = 24\text{V}$
Clamping Voltage	V_C		43		V	$I_{PP} = 1\text{A}$ (8 x 20 μs pulse)
Clamping Voltage	V_C			52	V	$I_{PP} = 7\text{A}$ (8 x 20 μs pulse)
Junction Capacitance	C_J		57		pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$
PTD322H35S36B35						
Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			36	V	
Breakdown Voltage	V_{BR}	40			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			1	μA	$V_{RWM} = 36\text{V}$
Clamping Voltage	V_C		63		V	$I_{PP} = 1\text{A}$ (8 x 20 μs pulse)
Clamping Voltage	V_C			80	V	$I_{PP} = 5\text{A}$ (8 x 20 μs pulse)
Junction Capacitance	C_J		35		pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

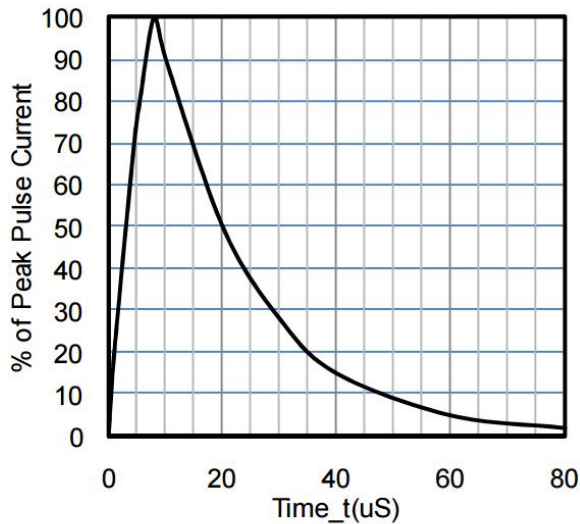
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



Peak Pulse Power vs. Pulse Time

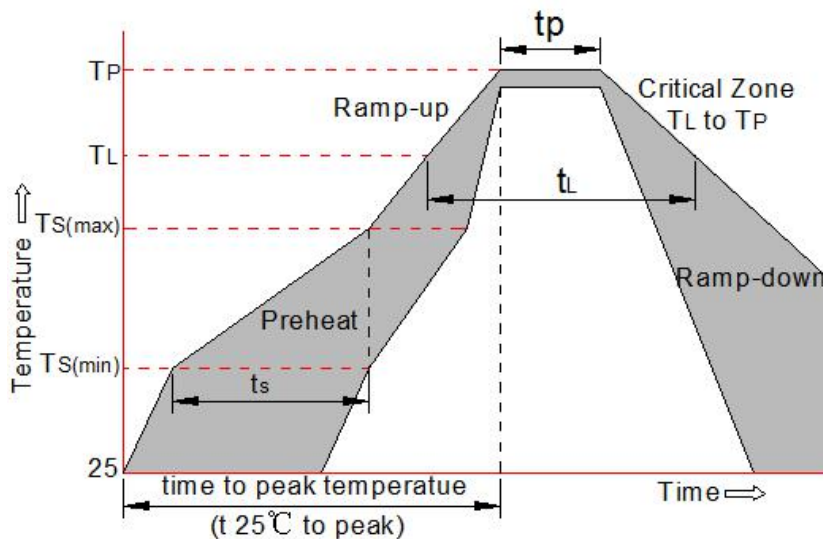


Power Derating Curve

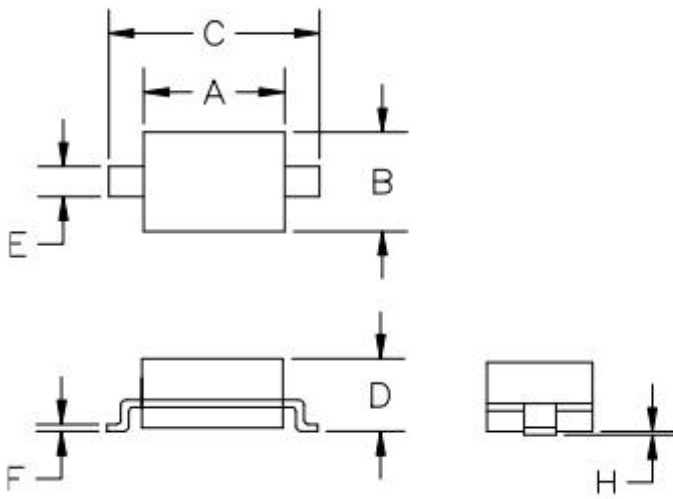


8 X 20uS Pulse Waveform

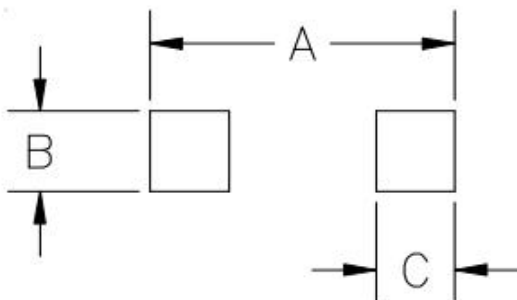
Reflow Condition		Pb-Free assembly (see as below)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150°C
	-Temperature Max($T_{s(max)}$)	+200°C
	-Time (Min to Max) (t_s)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3°C/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/sec. Max
Reflow	-Temperature(T_L) (Liquid us)	+217°C
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_P)		+260(+0/-5)°C
Time within 5°C of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6°C/sec. Max
Time 25°C to Peak Temp (T_P)		8 min. Max
Do not exceed		+260°C



Outline Drawing



SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.80	0.060	0.071
B	1.20	1.40	0.045	0.054
C	2.30	2.70	0.090	0.107
D	-	1.10	-	0.043
E	0.30	0.40	0.012	0.016
F	0.10	0.25	0.004	0.010
H	-	0.10	-	0.004



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031

Ordering information

Order code	Package	Base qty	Delivery mode
PTD322HXXB35	SOD323	3K	Tape and reel

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [ESD Suppressors / TVS Diodes](#) category:

Click to view products by [PROSEMI](#) manufacturer:

Other Similar products are found below :

[60KS200C](#) [D18V0L1B2LP-7B](#) [D5V0F4U5P5-7](#) [DESD5V0U1BB-7](#) [NTE4902](#) [P4KE27CA](#) [P6KE11CA](#) [P6KE39CA-TP](#) [P6KE8.2A](#)
[SA110CA](#) [SA60CA](#) [SA64CA](#) [SMBJ12CATR](#) [SMBJ33CATR](#) [SMBJ8.0A](#) [ESD101-B1-02ELS E6327](#) [ESD105-B1-02EL E6327](#) [ESD112-B1-02EL E6327](#) [ESD119B1W01005E6327XTSA1](#) [ESD5V0L1B02VH6327XTSA1](#) [ESD7451N2T5G](#) [19180-510](#) [CPDT-5V0USP-HF](#)
[3.0SMCJ33CA-F](#) [3.0SMCJ36A-F](#) [HSPC16701B02TP](#) [D3V3Q1B2DLP3-7](#) [D55V0M1B2WS-7](#) [DESD5V0U1BL-7B](#) [DRTR5V0U4SL-7](#)
[SCM1293A-04SO](#) [ESD200-B1-CSP0201 E6327](#) [SM12-7](#) [SMLJ45CA-TP](#) [CEN955 W/DATA](#) [82350120560](#) [VESD12A1A-HD1-GS08](#)
[CPDUR5V0R-HF](#) [CPDQC5V0U-HF](#) [CPDQC5V0USP-HF](#) [CPDQC5V0-HF](#) [D1213A-01LP4-7B](#) [D1213A-02WL-7](#) [MMAD1108/TR13](#)
[5KP100A](#) [5KP15A](#) [5KP18A](#) [5KP48A](#) [5KP90A](#) [5KP90CA](#)